

# 6 GHz RMS Power Detector with Digital Output

#### **FEATURES**

- Frequency Range: 10MHz to 6GHz
- Accurate Power Measurement of High Crest Factor (Up to 12dB) Waveforms
- 40dB Log Linear Dynamic Range
- Exceptional Accuracy Over Temperature
- Single-Ended RF Input
- 0.014dB/Bit (12-Bit) ADC Resolution (V<sub>RFF</sub> = 1.8V)
- ADC Sample Rate Up to 500ksps
- SPI/MICROWIRE Serial I/O
- Compatible with 1V to 3.6V Digital Logic
- Fast Response Time: 1µs Rise, 8µs Fall
- Low Power: 3mA at 3.3V and 500ksps
- Small 3mm × 3mm 12-pin DFN Package

#### **APPLICATIONS**

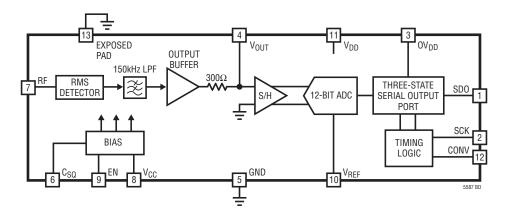
- LTE, WiMAX, W-CDMA, TD-SCDMA, CDMA, CDMA2000, EDGE, GSM
- Pico-Cells, Femto-Cells RF Power Control
- Wireless Repeaters
- CATV/DVB Transmitters
- MIMO Wireless Access Points
- Portable RMS Power Measurement
- Antenna Monitor

#### DESCRIPTION

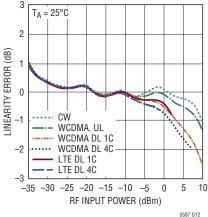
The LTC®5587 is a 10MHz to 6GHz, low power monolithic precision RMS power detector with an integrated 12-bit serial analog-to-digital converter (ADC). The RMS detector uses a proprietary technique to accurately measure the RF power of modulated signals with crest-factor as high as 12dB. For an input frequency of 2.14GHz the detection range is from -34dBm to 6dBm. The serial digital output of the detector is a 12-bit word value that is directly proportional to the RF signal power measured in dBm. The LTC5587 is suitable for precision power measurement for a wide variety of RF standards, including LTE, WiMAX, W-CDMA, TD-SCDMA, CDMA, CDMA2000, EDGE, GSM, etc. The DC output of the detector is connected in series with an on-chip  $300\Omega$  resistor to the analog output pin (V<sub>OLIT</sub>). This enables further filtering of the output modulation ripple using an off-chip capacitor before analog-todigital conversion. The ADC features include no data latency. no missing codes, and a sampling rate of up to 500ksps. A dedicated external reference pin ( $V_{RFF}$ ) can be tied to  $V_{DD}$ or other suitable low-impedance voltage reference to set the ADC full-scale input voltage range. The ADC also features an automatic power down after each conversion making the LTC5587 ideal for low-power applications.

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#### **BLOCK DIAGRAM**



# Linearity Error vs RF Input Power 2140MHz Modulated Waveforms



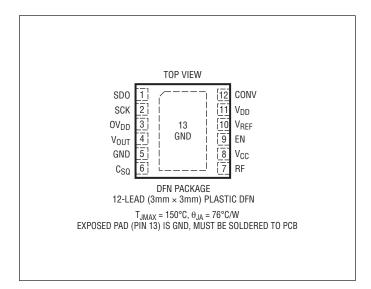
#### **ABSOLUTE MAXIMUM RATINGS**

#### (Note 1)

V <sub>DD</sub> , V <sub>CC</sub> Voltage, (Note 12)	4V
OV <sub>DD</sub> Supply Voltage	Min( $V_{DD} + 0.3V, 4V$ )
Maximum Input Signal Power (	
Maximum Input Signal Power (	Peak)25dBm
DC Voltage at RF	0.3V to 2V
V <sub>OUT</sub> Voltage	$-0.3V$ to $V_{DD} + 0.3V$
EN Voltage	$-0.3V$ to $V_{DD} + 0.3V$
SDO, SCK, CONV Voltage	$-0.3V$ to $V_{DD} + 0.3V$
V <sub>REF</sub> Voltage	$-0.3V$ to $V_{DD} + 0.3V$
Power Dissipation	100mW
Maximum Junction Temperatur	e, T <sub>JMAX</sub> 150°C
Operating Temperature Range (	Note 2)40°C to 85°C
Storage Temperature Range	65°C to 150°C

Caution: This part is sensitive to electrostatic discharge. It is very important that proper ESD precautions be observed when handling the LTC5587.

#### PIN CONFIGURATION



#### ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING	PART MARKING PACKAGE DESCRIPTION	
LTC5587IDD#PBF	LTC5587IDD#TRPBF	LFRH	12-Lead (3mm × 3mm) Plastic DFN	-40°C to 85°C

 $\label{lem:consult_LTC} \textbf{Consult LTC Marketing for parts specified with wider operating temperature ranges}.$ 

Consult LTC Marketing for information on non-standard lead based finish parts.

For more information on lead free part marking, go to: http://www.linear.com/leadfree/

For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/

# **ELECTRICAL CHARACTERISTICS** The $\bullet$ denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$ (Note 2). $V_{CC} = V_{DD} = 0V_{DD} = 3.3V$ , $V_{REF} = 1.8V$ , EN = 3.3V, $f_{SMPL} = f_{SMPL(MAX)}$ and $f_{SCK} = f_{SCK(MAX)}$ unless otherwise noted. Test circuit is shown in Figure 1.

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
RF Input						
Input Frequency Range (Note 4)				10 to 6000		MHz
Input Impedance				205  1.6		$\Omega  pF$
f <sub>RF</sub> = 450MHz						
RF Input Power Range	Externally Matched to $50\Omega$ Source			-34 to 6		dBm
Linear Dynamic Range, CW (Note 3) ±1dB Linearity Error				40		dB
Linear Dynamic Range, CDMA (Note 3)	±1dB Linearity Error; CDMA 4-Carrier			40		dB
Output Slope				73		LSB/dB
Logarithmic Intercept (Note 5)				-42		dBm
Output Variation vs Temperature	Temperature Normalized to Output at $25^{\circ}$ C; $P_{IN} = -34$ dBm to 6dBm $\pm 1$		±1		dB	



**ELECTRICAL CHARACTERISTICS** The  $\bullet$  denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^{\circ}C$  (Note 2).  $V_{CC} = V_{DD} = 0V_{DD} = 3.3V$ ,  $V_{REF} = 1.8V$ , EN = 3.3V,  $f_{SMPL} = f_{SMPL(MAX)}$  and  $f_{SCK} = f_{SCK(MAX)}$  unless otherwise noted. Test circuit is shown in Figure 1.

Dupty Variation vs Temperature   Normalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm   ±0.5   dB	PARAMETER	CONDITIONS	MIN TYP	MAX UNITS
Pin = -34d8m to Od8m	Output Variation vs Temperature	Normalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm	±0.5	dB
2nd Order Harmonic Distortion				
3rd Order Harmonic Distortion		·		
RF   Finpur   Power Range   CW   Input: Externally Matched to SOΩ Source   -34 to 6   dBm				
RF Input Power Range   CW Input: Externally Matched to 50Ω Source   -34 to 6   dBm		At RF Input; CW Input; P <sub>IN</sub> = 0dBm	-52	dBc
Linear Dynamic Range, CW (Note 3)				
Linear Dynamic Range, EDGE (Note 3)         ±1dB Linearity Error; EDGE 3π/8-Shifted 8PSK         40         dB           Output Slope         73         LS8/dB           Logarithmic Intercept (Note 5)         −42         dBm           Output Variation vs Temperature         Normalized to Output at 25°C; P <sub>IN</sub> = −34dBm to 6dBm         ±1         dB           Output Variation vs Temperature         Normalized to Output at 25°C; P <sub>IN</sub> = −27dBm to −10dBm         ±0.5         dB           Deviation from CW Response; P <sub>N</sub> = 54dBm to 6dBm         ±0.1         dB           Fine = 2440MHz         EDGE 3π/8 Shifted 8PSK         ±0.1         dB           Fine Paper Range         CW Input: Externally Matched to 50Ω Source         −34 to 6         dBm           Linear Dynamic Range, CW (Mote 3)         ±1dB Linearity Error; 4-Carrier WCDMA         37         dB           Linear Dynamic Range, WCDMA (Note 3)         ±1dB Linearity Error; 4-Carrier WCDMA         37         dB           Linear Dynamic Range, WCDMA (Note 3)         ±1dB Linearity Error; 4-Carrier WCDMA         37         dB           Untput Variation vs Temperature         Normalized to Output at 25°C; P <sub>IN</sub> = −34dBm to 6dBm         ±1         dB           Deviation from CW Response;         WCDMA 1-Carrier Uplink         ±0.5         dB           P <sub>IN</sub> = 24dBm to -4dBm	· · · · · · · · · · · · · · · · · · ·	' '	-34 to 6	
Output Variation vs Temperature   Normalized to Output at 25°C; P <sub>IN</sub> = -34dBm to 6dBm		-		
Logarithmic Intercept (Note 5)         —42         dBm           Output Variation vs Temperature         Normalized to Output at 25°C; P <sub>IN</sub> = -34dBm to 6dBm         ±1         dB           Output Variation vs Temperature         Normalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm         ±0.5         dB           Deviation from CW Response; Plm = -34dBm to 6dBm         ±0.1         dB           Plm = -34dBm to 6dBm         ±1.0         dB           Linear Dynamic Range, CW (Note 3)         ±1dB Linearity Error; 4-Carrier WCDMA         37         dB           Linear Dynamic Range, CW (Note 3)         ±1dB Linearity Error; 4-Carrier WCDMA         37         dB           Output Variation vs Temperature         Normalized to Output at 25°C; P <sub>IN</sub> = -34dBm to 6dBm         ±1         dB           Output Variation vs Temperature         Normalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm         ±0.5<	Linear Dynamic Range, EDGE (Note 3)	±1dB Linearity Error; EDGE 3π/8-Shifted 8PSK		
Output Variation vs Temperature         Normalized to Output at 25°C; P <sub>IN</sub> = -34dBm to 6dBm         ±1         dB           Output Variation vs Temperature         Normalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm         ±0.5         dB           Deviation from CW Response; PIN = -34dBm to 6dBm         EDGE 3π/8 Shifted 8PSK         ±0.1         dB           FIN = -34dBm to 6dBm         #0.1         dB         dB           Fin put Power Range         CW Input: Externally Matched to 50Ω Source         -34 to 6         dBm           Linear Dynamic Range, CW (Note 3)         ±1dB Linearity Error         43         dB           Linear Dynamic Range, WCDMA (Note 3)         ±1dB Linearity Error; 4-Carrier WCDMA         37         dB           Output Slope         73         LS8/dB         LS8/dB           Logarithmic Intercept (Note 5)         -42         dBm           Output Variation vs Temperature         Normalized to Output at 25°C; PIN = -34dBm to 6dBm         ±1         dB           Deviation from CW Response;         WCDMA 1-Carrier Uplink         ±0.5         dB           Deviation from CW Response;         WCDMA 64-Channel 4-Carrier Downlink         ±0.5         dB           Inear Dynamic Range, CW (Note 3)         ±1dB Linearity Error         40         dB           Linear Dynamic Range, CW (Note 3)	Output Slope		73	LSB/dB
Output Variation vs Temperature         Normalized to Output at $25^{\circ}$ C; $P_{IN} = -27 dBm$ to $-10 dBm$ $\pm 0.5$ dB           Deviation from CW Response; $P_{IN} = -34 dBm$ to $60 dBm$ EDGE $3\pi/8$ Shifted 8PSK $\pm 0.1$ dB           Fin Fin Power Range         CW Input: Externally Matched to $50\Omega$ Source $-34$ to $6$ dBm           Linear Dynamic Range, CW (Note 3) $\pm 1 dB$ Linearity Error $43$ dB           Linear Dynamic Range, WCDMA (Note 3) $\pm 1 dB$ Linearity Error; $\pm 4 + 4 + 4 + 4 + 4 + 4 + 4 + 4 + 4 + 4 $	Logarithmic Intercept (Note 5)		-42	dBm
Deviation from CW Response; PIN = -34dBm to 6dBm	Output Variation vs Temperature	Normalized to Output at 25°C; P <sub>IN</sub> = -34dBm to 6dBm	±1	dB
PIN = -34dBm to 6dBm       CM Input: Externally Matched to 50Ω Source       -34 to 6       dBm         Linear Dynamic Range, CW (Note 3)       ±1dB Linearity Error       43       dB         Linear Dynamic Range, WCDMA (Note 3)       ±1dB Linearity Error; 4-Carrier WCDMA       37       dB         Output Slope       73       LSB/dB         Logarithmic Intercept (Note 5)       -42       dBm         Output Variation vs Temperature       Normalized to Output at 25°C; PIN = -34dBm to 6dBm       ±1       dB         Output Variation vs Temperature       Normalized to Output at 25°C; PIN = -27dBm to -10dBm       ±0.5       dB         Deviation from CW Response;       WCDMA 1-Carrier Uplink       ±0.1       dB         PIN = -34dBm to -4dBm       ±0.5       dB         VEDMA 1-Carrier Uplink       ±0.5       dB         VEDMA 64-Channel 4-Carrier Downlink       ±0.5       dB         Inser 2600MHz       ER       20.1       dB         RF Input Power Range       CW Input: Externally Matched to 50Ω Source       -34 to 6       dBm         Linear Dynamic Range, CW (Note 3)       ±1dB Linearity Error       40       dB         Output Variation vs Temperature       Normalized to Output at 25°C; PIN = -34dBm to 6dBm       ±1       dB         Output Variation vs Tempe	Output Variation vs Temperature	Normalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm	±0.5	dB
RF   Input Power Range   CW   Input: Externally Matched to 50Ω Source   -34 to 6   dBm		EDGE 3π/8 Shifted 8PSK	±0.1	dB
Linear Dynamic Range, CW (Note 3)	f <sub>RF</sub> = 2140MHz			
Linear Dynamic Range, WCDMA (Note 3)       ±1dB Linearity Error; 4-Carrier WCDMA       37       dB         Output Slope       73       LSB/dB         Logarithmic Intercept (Note 5)       -42       dBm         Output Variation vs Temperature       Normalized to Output at 25°C; P <sub>IN</sub> = -34dBm to 6dBm       ±1       dB         Output Variation vs Temperature       Normalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm       ±0.5       dB         Deviation from CW Response; P <sub>IN</sub> = -34dBm to -4dBm       WCDMA 1-Carrier Uplink WCDMA 64-Channel 4-Carrier Downlink       ±0.1       dB         P <sub>IN</sub> = -346Bm to -4dBm       WCDMA 64-Channel 4-Carrier Downlink       ±0.5       dB         Inear Dynamic Range, CW (Note 3)       ±1dB Linearity Error       40       dB         Output Slope       73       LSB/dB         Logarithmic Intercept (Note 5)       -42       dBm         Output Variation vs Temperature       Normalized to Output at 25°C; P <sub>IN</sub> = -34dBm to 6dBm       ±1       dB         Output Variation vs Temperature       Normalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm       ±0.5       dB         Deviation from CW Response; P <sub>IN</sub> = -34dBm to 2dBm       WiMax OFDMA Preamble WiMax OFDMA Burst       ±0.5       dB         Deviation from CW Response; P <sub>IN</sub> = -34dBm to 2dBm       WiMax OFDMA Preamble WiMax OFDMA Bu	RF Input Power Range	CW Input: Externally Matched to $50\Omega$ Source	-34 to 6	dBm
Output Slope       73       LSB/dB         Logarithmic Intercept (Note 5) $-42$ dBm         Output Variation vs Temperature       Normalized to Output at 25°C; P <sub>IN</sub> = -34dBm to 6dBm       ±1       dB         Output Variation vs Temperature       Normalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm       ±0.5       dB         Deviation from CW Response;       WCDMA 1-Carrier Uplink       ±0.1       dB         P <sub>IN</sub> = -34dBm to -4dBm       WCDMA 64-Channel 4-Carrier Downlink       ±0.5       dB         Ingre = 2600MHz       CW Input: Externally Matched to 50Ω Source       -34 to 6       dBm         Linear Dynamic Range, CW (Note 3)       ±1dB Linearity Error       40       dB         Output Slope       73       LSB/dB         Logarithmic Intercept (Note 5)       -42       dBm         Output Variation vs Temperature       Normalized to Output at 25°C; P <sub>IN</sub> = -34dBm to 6dBm       ±1       dB         Output Variation vs Temperature       Normalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm       ±0.5       dB         Deviation from CW Response;       WiMax OFDMA Preamble       ±0.1       dB         P <sub>IN</sub> = -34dBm to 2dBm       WiMax OFDM Burst       ±0.5       dB         Insert P <sub>IN</sub> = -34dBm to 2dBm       WiMax OFDM Burst       ±0.5       dB	Linear Dynamic Range, CW (Note 3)	±1dB Linearity Error	43	dB
Logarithmic Intercept (Note 5)-42dBmOutput Variation vs TemperatureNormalized to Output at 25°C; P <sub>IN</sub> = -34dBm to 6dBm±1dBOutput Variation vs TemperatureNormalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm±0.5dBDeviation from CW Response; P <sub>IN</sub> = -34dBm to -4dBmWCDMA 1-Carrier Uplink WCDMA 64-Channel 4-Carrier Downlink±0.1dBF <sub>IN</sub> = -34dBm to -4dBmWCDMA 64-Channel 4-Carrier Downlink±0.5dBF <sub>IR</sub> = 2600MHzRF Input Power RangeCW Input: Externally Matched to 50Ω Source-34 to 6dBmLinear Dynamic Range, CW (Note 3)±1dB Linearity Error40dBOutput Slope73LSB/dBLogarithmic Intercept (Note 5)-42dBmOutput Variation vs TemperatureNormalized to Output at 25°C; P <sub>IN</sub> = -34dBm to 6dBm±1dBOutput Variation vs TemperatureNormalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm±0.5dBDeviation from CW Response; P <sub>IN</sub> = -34dBm to 2dBmWiMax OFDMA Preamble WiMax OFDM Burst±0.1dBDeviation from CW Response; WiMax OFDM Burst±0.5dB1g <sub>F</sub> = 3500MHzRF Input Power RangeCW Input: Externally Matched to 50Ω Source-30 to 6dBmLinear Dynamic Range, CW (Note 3)±1dB Linearity Error36dBOutput Slope73LSB/dB	Linear Dynamic Range, WCDMA (Note 3)	±1dB Linearity Error; 4-Carrier WCDMA	37	dB
Output Variation vs Temperature         Normalized to Output at 25°C; $P_{IN} = -34dBm$ to 6dBm         ±1         dB           Output Variation vs Temperature         Normalized to Output at 25°C; $P_{IN} = -27dBm$ to $-10dBm$ ±0.5         dB           Deviation from CW Response; $P_{IN} = -34dBm$ to $-4dBm$ WCDMA 1-Carrier Uplink         ±0.1         dB $P_{IN} = -34dBm$ to $-4dBm$ WCDMA 64-Channel 4-Carrier Downlink         ±0.5         dB $P_{IN} = -34dBm$ to $-4dBm$ WCDMA 64-Channel 4-Carrier Downlink         ±0.5         dB $P_{IN} = -34dBm$ to $-4dBm$ WCDMA 64-Channel 4-Carrier Downlink         ±0.5         dB $P_{IN} = -34dBm$ to Power Range         CW Input: Externally Matched to $50\Omega$ Source $-34$ to 6         dBm           Output Slope         T3         LSB/dB         LSB/dB           Output Variation vs Temperature         Normalized to Output at 25°C; $P_{IN} = -34dBm$ to 6dBm         ±1         dB           Output Variation vs Temperature         Normalized to Output at 25°C; $P_{IN} = -27dBm$ to $-10dBm$ ±0.5         dB           Deviation from CW Response; $P_{IN} = -34dBm$ to 2dBm         WiMax OFDMA Preamble WiMax OFDMA Preamble WiMax OFDM Burst         ±0.1         dB $P_{IN} = -3500MHz$ WI Input: Externally Matched to $50\Omega$ Source $-30$ to	Output Slope		73	LSB/dB
Output Variation vs TemperatureNormalized to Output at $25^{\circ}$ C; $P_{IN} = -27dBm$ to $-10dBm$ $\pm 0.5$ dBDeviation from CW Response; $P_{IN} = -34dBm$ to $-4dBm$ WCDMA 1-Carrier Uplink WCDMA 64-Channel 4-Carrier Downlink $\pm 0.1$ dB $f_{RF} = 2600MHz$ The special of the special output Suppose the special output SlopeCW Input: Externally Matched to $50\Omega$ Source $-34$ to 6dBmLinear Dynamic Range, CW (Note 3) $\pm 1dB$ Linearity Error40dBOutput Slope73LSB/dBLogarithmic Intercept (Note 5) $-42$ dBmOutput Variation vs TemperatureNormalized to Output at $\pm 25^{\circ}$ C; $P_{IN} = -34dBm$ to $\pm 6dBm$ $\pm 1$ dBOutput Variation vs TemperatureNormalized to Output at $\pm 25^{\circ}$ C; $P_{IN} = -27dBm$ to $\pm 10dBm$ $\pm 0.5$ dBDeviation from CW Response; $P_{IN} = -34dBm$ to $\pm 2dBm$ $\pm 0.5$ dBDeviation from CW Response; $P_{IN} = -34dBm$ to $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$ $P_{IN} = -34dBm$ to $\pm 2dBm$ $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$ $P_{IN} = -34dBm$ to $\pm 2dBm$ $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$ $P_{IN} = -34dBm$ to $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$ $P_{IN} = -34dBm$ to $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$ $P_{IN} = -34dBm$ to $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$ $P_{IN} = -34dBm$ $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$ $P_{IN} = -34dBm$ $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$ $\pm 10dBm$	Logarithmic Intercept (Note 5)		-42	dBm
Deviation from CW Response; $P_{IN} = -34dBm$ to $-4dBm$ WCDMA 1-Carrier Uplink WCDMA 64-Channel 4-Carrier Downlink±0.1 ±0.5dB $f_{RF} = 2600MHz$ RF Input Power RangeCW Input: Externally Matched to $50\Omega$ Source $-34$ to 6dBmLinear Dynamic Range, CW (Note 3)±1dB Linearity Error40dBOutput Slope73LSB/dBLogarithmic Intercept (Note 5) $-42$ dBmOutput Variation vs TemperatureNormalized to Output at $25^{\circ}$ C; $P_{IN} = -34dBm$ to $60dBm$ ±1dBOutput Variation vs TemperatureNormalized to Output at $25^{\circ}$ C; $P_{IN} = -27dBm$ to $-10dBm$ ±0.5dBDeviation from CW Response; $P_{IN} = -34dBm$ to $2dBm$ ±0.1dBDeviation from CW Response; $P_{IN} = -34dBm$ to $2dBm$ ±0.5dB $P_{IN} $	Output Variation vs Temperature	Normalized to Output at 25°C; P <sub>IN</sub> = -34dBm to 6dBm	±1	dB
$P_{IN} = -34dBm$ to $-4dBm$ WCDMA 64-Channel 4-Carrier Downlink $\pm 0.5$ dB $f_{RF} = 2600MHz$ RF Input Power RangeCW Input: Externally Matched to $50\Omega$ Source $-34$ to 6dBmLinear Dynamic Range, CW (Note 3) $\pm 1dB$ Linearity Error $\pm 1dB$ $\pm 1dB$ Output Slope73LSB/dBLogarithmic Intercept (Note 5) $-42$ dBmOutput Variation vs TemperatureNormalized to Output at $\pm 25^{\circ}$ C; $\pm 100^{\circ}$ C; $\pm 100^{\circ}$ C $\pm 100^{\circ}$ CdBOutput Variation vs TemperatureNormalized to Output at $\pm 100^{\circ}$ C $\pm 100^{\circ}$ CdBDeviation from CW Response; PIN = $-34$ dBm to $\pm 100^{\circ}$ C $\pm 100^{\circ}$ CdB $\pm 100^{\circ}$ CWiMax OFDMA Preamble WiMax OFDM Burst $\pm 100^{\circ}$ CdB $\pm 100^{\circ}$ C $\pm 100^{\circ}$ C $\pm 100^{\circ}$ CdB $\pm 100^{\circ}$ C $\pm 100^{\circ}$ C $\pm 100^{\circ}$ C $\pm 100^{\circ}$ CdB $\pm 100^{\circ}$ C $\pm 100^{\circ}$ COutput Slope $\pm 100^{\circ}$ C <td< td=""><td>Output Variation vs Temperature</td><td>Normalized to Output at 25°C; P<sub>IN</sub> = -27dBm to -10dBm</td><td>±0.5</td><td>dB</td></td<>	Output Variation vs Temperature	Normalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm	±0.5	dB
RF Input Power RangeCW Input: Externally Matched to $50\Omega$ Source $-34$ to $6$ dBmLinear Dynamic Range, CW (Note 3) $\pm 1$ dB Linearity Error $40$ dBOutput Slope $73$ LSB/dBLogarithmic Intercept (Note 5) $-42$ dBmOutput Variation vs TemperatureNormalized to Output at $25^{\circ}$ C; $P_{IN} = -34$ dBm to $6$ dBm $\pm 1$ dBOutput Variation vs TemperatureNormalized to Output at $25^{\circ}$ C; $P_{IN} = -27$ dBm to $-10$ dBm $\pm 0.5$ dBDeviation from CW Response; $P_{IN} = -34$ dBm to $2$ dBm $\pm 0.1$ dBWiMax OFDMA Preamble WiMax OFDM Burst $\pm 0.5$ dB $1$ fr = $3500$ MHzRF Input Power RangeCW Input: Externally Matched to $50\Omega$ Source $-30$ to $6$ dBmLinear Dynamic Range, CW (Note 3) $\pm 1$ dB Linearity Error $36$ dBOutput Slope $73$ LSB/dB				
Linear Dynamic Range, CW (Note 3) $\pm 1$ dB Linearity Error40dBOutput Slope73LSB/dBLogarithmic Intercept (Note 5) $-42$ dBmOutput Variation vs TemperatureNormalized to Output at 25°C; $P_{IN} = -34$ dBm to 6dBm $\pm 1$ dBOutput Variation vs TemperatureNormalized to Output at 25°C; $P_{IN} = -27$ dBm to $-10$ dBm $\pm 0.5$ dBDeviation from CW Response; $P_{IN} = -34$ dBm to 2dBmWiMax OFDMA Preamble WiMax OFDM Burst $\pm 0.1$ $\pm 0.5$ dB $f_{RF} = 3500$ MHzRF Input Power RangeCW Input: Externally Matched to $50\Omega$ Source $-30$ to 6dBmLinear Dynamic Range, CW (Note 3) $\pm 1$ dB Linearity Error36dBOutput Slope73LSB/dB	f <sub>RF</sub> = 2600MHz			
Output Slope       73       LSB/dB         Logarithmic Intercept (Note 5) $-42$ dBm         Output Variation vs Temperature       Normalized to Output at 25°C; $P_{IN} = -34dBm$ to 6dBm $\pm 1$ dB         Output Variation vs Temperature       Normalized to Output at 25°C; $P_{IN} = -27dBm$ to $-10dBm$ $\pm 0.5$ dB         Deviation from CW Response; $P_{IN} = -34dBm$ to 2dBm       WiMax OFDMA Preamble WiMax OFDM Burst $\pm 0.1$ dB $P_{IN} = -34dBm$ to 2dBm       WiMax OFDM Burst $\pm 0.5$ dB $P_{IN} = -3500MHz$ $P_{IN} = -3500MHz$ $P_{IN} = -300MHz$ $P_{IN} = -300MHz$ $P_{IN} = -300MHz$ RF Input Power Range       CW Input: Externally Matched to $P_{IN} = -300M$ to $P_{IN} =$	RF Input Power Range	CW Input: Externally Matched to $50\Omega$ Source	-34 to 6	dBm
Logarithmic Intercept (Note 5) $-42$ dBmOutput Variation vs TemperatureNormalized to Output at 25°C; $P_{IN} = -34dBm$ to 6dBm $\pm 1$ dBOutput Variation vs TemperatureNormalized to Output at 25°C; $P_{IN} = -27dBm$ to $-10dBm$ $\pm 0.5$ dBDeviation from CW Response; $P_{IN} = -34dBm$ to 2dBmWiMax OFDMA Preamble WiMax OFDM Burst $\pm 0.1$ dB $f_{RF} = 3500MHz$ RF Input Power RangeCW Input: Externally Matched to $50\Omega$ Source $-30$ to 6dBmLinear Dynamic Range, CW (Note 3) $\pm 1dB$ Linearity Error36dBOutput Slope73LSB/dB	Linear Dynamic Range, CW (Note 3)	±1dB Linearity Error	40	dB
Output Variation vs Temperature       Normalized to Output at 25°C; $P_{IN} = -34dBm$ to 6dBm       ±1       dB         Output Variation vs Temperature       Normalized to Output at 25°C; $P_{IN} = -27dBm$ to $-10dBm$ ±0.5       dB         Deviation from CW Response; $P_{IN} = -34dBm$ to 2dBm       WiMax OFDMA Preamble WiMax OFDM Burst       ±0.1       dB $P_{IN} = -34dBm$ to 2dBm       WiMax OFDM Burst       ±0.5       dB $P_{IN} = -34dBm$ to 2dBm       CW Input: Externally Matched to 50Ω Source       -30 to 6       dBm         RF Input Power Range       CW Input: Externally Matched to 50Ω Source       -30 to 6       dBm         Linear Dynamic Range, CW (Note 3)       ±1dB Linearity Error       36       dB         Output Slope       73       LSB/dB	Output Slope		73	LSB/dB
Output Variation vs Temperature       Normalized to Output at 25°C; $P_{IN} = -27 dBm$ to $-10 dBm$ ±0.5       dB         Deviation from CW Response; $P_{IN} = -34 dBm$ to 2dBm       WiMax OFDMA Preamble WiMax OFDM Burst       ±0.1       dB $P_{IN} = -34 dBm$ to 2dBm       WiMax OFDM Burst       ±0.5       dB $P_{IN} = -34 dBm$ to 2dBm       CW Input: Externally Matched to 50Ω Source       -30 to 6       dBm         Einear Dynamic Range, CW (Note 3)       ±1dB Linearity Error       36       dB         Output Slope       73       LSB/dB	Logarithmic Intercept (Note 5)		-42	dBm
Deviation from CW Response;       WiMax OFDMA Preamble $\pm 0.1$ dB $P_{IN} = -34dBm$ to 2dBm       WiMax OFDM Burst $\pm 0.5$ dB         f <sub>RF</sub> = 3500MHz         RF Input Power Range       CW Input: Externally Matched to $50\Omega$ Source $-30$ to 6       dBm         Linear Dynamic Range, CW (Note 3) $\pm 1dB$ Linearity Error       36       dB         Output Slope       73       LSB/dB	Output Variation vs Temperature	Normalized to Output at 25°C; P <sub>IN</sub> = -34dBm to 6dBm	±1	dB
$P_{IN} = -34 dBm$ to 2dBmWiMax OFDM Burst±0.5dB $f_{RF} = 3500MHz$ RF Input Power RangeCW Input: Externally Matched to $50\Omega$ Source $-30$ to 6dBmLinear Dynamic Range, CW (Note 3)±1dB Linearity Error36dBOutput Slope73LSB/dB	Output Variation vs Temperature	Normalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm ±0.5		dB
RF Input Power Range     CW Input: Externally Matched to 50Ω Source     -30 to 6     dBm       Linear Dynamic Range, CW (Note 3)     ±1dB Linearity Error     36     dB       Output Slope     73     LSB/dB				
Linear Dynamic Range, CW (Note 3) ±1dB Linearity Error 36 dB Output Slope 73 LSB/dB	f <sub>RF</sub> = 3500MHz			<del>.</del>
Output Slope 73 LSB/dB	RF Input Power Range	CW Input: Externally Matched to $50\Omega$ Source	-30 to 6	dBm
	Linear Dynamic Range, CW (Note 3)	±1dB Linearity Error	36	dB
Logarithmic Intercept (Note 5) —40 dBm	Output Slope		73	LSB/dB
	Logarithmic Intercept (Note 5)		-40	dBm



**ELECTRICAL CHARACTERISTICS** The  $\bullet$  denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^{\circ}C$  (Note 2).  $V_{CC} = V_{DD} = 0V_{DD} = 3.3V$ ,  $V_{REF} = 1.8V$ , EN = 3.3V,  $f_{SMPL} = f_{SMPL(MAX)}$  and  $f_{SCK} = f_{SCK(MAX)}$  unless otherwise noted. Test circuit is shown in Figure 1.

PARAMETER		CONDITIONS			MIN	TYP	MAX	UNITS
Output Variation	vs Temperature	Normalized to O	utput at $25^{\circ}$ C; $P_{IN} = -30$ dBm to 6dBm			±1		dB
Output Variation	vs Temperature	Normalized to O	Normalized to Output at 25°C; P <sub>IN</sub> = -27dBm to -10dBm			±0.5		dB
Deviation from CV $P_{IN} = -34dBm$ to		WiMax OFDMA WiMax OFDM B	/iMax OFDMA Preamble			±0.1 ±0.5		dB dB
Detector Analog		WINIAX OI DIVI D	urot			10.0		U
Output DC Voltag		No Signal Applie	ed to RF Input			180		mV
Output Impedance			Resistor Allows for Off-Chip Filter Cap			300		Ω
Output Current S						5/5		mA
Rise Time (1000p	oF on V <sub>OUT</sub> )	0.2V to 1.6V, 10	% to 90%, f <sub>RF</sub> = 2140MHz			1		μsec
Fall Time (1000pl	F on V <sub>OUT</sub> )	1.6V to 0.2V, 10	% to 90%, f <sub>RF</sub> = 2140MHz			8		μsec
Power Supply Re	jection Ratio (Note 6)	For CW RF Inpu	t Over Operating Input Power Range			49		dB
Integrated Output	t Voltage Noise	1 to 6.5 kHz Inte	gration BW, P <sub>IN</sub> = 0dBm CW			150		μV <sub>RMS</sub>
Peak-to-Peak AD	C Output Noise	C <sub>FILT</sub> = 1000pF, F	P <sub>IN</sub> = 0dBm CW			11		LSB
ADC Resolution								
ADC Resolution		(No Missing Cod	des)	•	12			Bits
Differential Linear	rity Error	EN = 0V, Voltage	on $V_{OUT} = 0V$ to 1.8V, $V_{REF} = 1.8V$	•		±0.25	±1	LSB
Measurement Re	solution	1LSB = V <sub>REF</sub> /(40	096 • 32mV/dB), V <sub>REF</sub> = 1.8V			0.014		dB/Bit
ADC Digital Timi	ng							
SYMBOL	PARAMETER		CONDITIONS		MIN	ТҮР	MAX	UNITS
f <sub>SAMPL(MAX)</sub>	Maximum Sampling Frequ	uency	(Notes 8, 9)	•	500			kHz
f <sub>SCK</sub>	Shift Clock Frequency		(Notes 8, 9)	•			50	MHz
t <sub>SCK</sub>	Shift Clock Period			•	20			ns
t <sub>THROUGHPUT</sub>	Minimum Throughput Tin	ne, t <sub>ACQ</sub> + t <sub>CONV</sub>		•			2	μs
t <sub>ACQ</sub>	Acquisition Time			•	0.5			μѕ
t <sub>CONV</sub>	Conversion Time			•	1.5			μs
<u>t</u> 1	Minimum Positive CONV		(Note 8)	•	1.5			μs
t <sub>2</sub>	SCK↑ Setup Time After Co	-	(Note 8)	•	16			ns
t <sub>3</sub>	SDO Enabled Time After C		(Notes 8, 9)	•			16	ns
t <sub>4</sub>	SDO Data Valid Access Ti	me After SCK↓	(Notes 8, 9, 10)	•	400/		8	ns 
-	t <sub>5</sub> SCK Low Time		(Note 7)	•	40%			t <sub>SCK</sub>
t <sub>6</sub> SCK High Time		(Note 7)	•	40%			t <sub>SCK</sub>	
<u>t</u> <sub>7</sub>	SDO Data Valid Hold Time	<u>*</u>	(Notes 8, 9, 10)	•	4			ns
t <sub>8</sub> SDO Into Hi-Z State Time After CONV↑  ADC Digital Inputs and Outputs		(Notes 8, 9)			6		ns	
SYMBOL	PARAMETER		CONDITIONS		MIN	ТҮР	MAX	UNITS
	SCK, CONV Logic High In	nut	CONDITIONS		2	ITP	IVIAX	V
$\frac{V_{IH}}{V_{IL}}$	SCK, CONV Logic Fight III	•		•			0.8	V
	Logic High Input Current	Jul	SCK, CONV = V <sub>DD</sub>				2.5	v μΑ
I <sub>IH</sub>			SCK, CONV = VDD		-2.5		۷.۵	μA μA
'IL	Logio Low illhut oullellt	I <sub>IL</sub> Logic Low Input Current			۷.۵			μΑ

LINEAR TECHNOLOGY **ELECTRICAL CHARACTERISTICS** The ullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^{\circ}\text{C}$  (Note 2).  $V_{CC} = V_{DD} = 0V_{DD} = 3.3V$ ,  $V_{REF} = 1.8V$ , EN = 3.3V,  $f_{SMPL} = f_{SMPL(MAX)}$  and  $f_{SCK} = f_{SCK(MAX)}$  unless otherwise noted. Test circuit is shown in Figure 1.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
C <sub>IN</sub>	SCK, CONV Input Capacitance				2		pF
V <sub>OH</sub>	SDO Logic High Output	I <sub>SOURCE</sub> = 200μA	•	V <sub>DD</sub> - 0.2			V
$V_{OL}$	SDO Logic Low Output	I <sub>SINK</sub> = 200μA	•			0.2	V
I <sub>OZ</sub>	Hi-Z Output Leakage	CONV = V <sub>DD</sub>	•			±3	μА
$C_{0Z}$	Hi-Z Output Capacitance	CONV = V <sub>DD</sub>			4		pF
I <sub>SOURCE</sub>	SDO Source Current	SDO Connected to GND = 0V			-10		mA
I <sub>SINK</sub>	SDO Sink Current	SDO Connected to V <sub>DD</sub>			10		mA

Detector Enable (EN) Low = Off, High = On

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
EN Input High Voltage (On)		•	2			V
EN Input Low Voltage (Off)		•			0.3	V
Enable Pin Input Current	EN = 3.3V			25		μA
Turn ON Time; CW RF Input	V <sub>OUT</sub> within 10% of Final Value; P <sub>IN</sub> = 0dBm			1		μs
Turn OFF Time; CW RF Input	V <sub>OUT</sub> < 0.18V; P <sub>IN</sub> = 0dBm			8		μs
Power Supply	·					
OV <sub>DD</sub> Supply Voltage		•	1	3.3	$V_{DD}$	V
V <sub>DD</sub> Supply Voltage		•	2.7	3.3	3.6	V
V <sub>REF</sub> Reference Voltage		•	1.4		V <sub>DD</sub> + 0.05	V
V <sub>CC</sub> Supply Voltage	Should Be Equal to V <sub>DD</sub>	•	2.7	3.3	3.6	V
Total Supply Current	No RF Input Signal, ADC Operational at 500ksps No RF Input Signal, ADC Sleep-Mode	•		3 1.4	4 2.5	mA mA
Shutdown Current	EN = 0.3V, CONV = 3.3V, ADC Sleep-Mode			0.2	10	μA

**Note 1:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime. The maximum RF input power rating is guaranteed by design and engineering characterization, but not production tested.

**Note 2:** The LTC5587 is guaranteed to be functional over the operating temperature range from -40°C to 85°C.

**Note 3:** The linearity error is calculated by the difference between the incremental slope of the output and the average output slope from –20dBm to 0dBm. The dynamic range is defined as the range over which the linearity error is within ±1dB.

**Note 4:** An external capacitor at the  $C_{SQ}$  pin should be used for input frequencies below 250MHz. Without this capacitor, lower frequency operation results in excessive RF ripple in the output voltage.

**Note 5:** Logarithmic intercept is an extrapolated input power level from the best fitted log-linear straight line, where the converted output code is OLSB.

**Note 6:** PSRR determined as the dB value of the change in converted output voltage over the change in  $V_{CC}$  supply voltage at a given CW input power level.

Note 7: Guaranteed by design not subject to test.

**Note 8:** Guaranteed by characterization. All input signals are specified with  $t_B = t_F = 2ns$  (10% to 90% of  $V_{DD}$ ) and timed from a voltage level of 1.6V.

**Note 9:** All timing specifications given are with a 10pF capacitance load. With a capacitance load greater than this value, a digital buffer or latch must be used.

**Note 10:** The time required for the output to cross the  $V_{IH}$  or  $V_{IL}$  voltage.

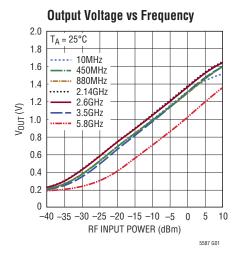
**Note 11:** When pins  $V_{OUT}$  and  $V_{REF}$  are taken below GND or above  $V_{DD}$ , they will be clamped by internal diodes. This product can handle input currents greater than 100mA below GND or above  $V_{DD}$  without latchup.

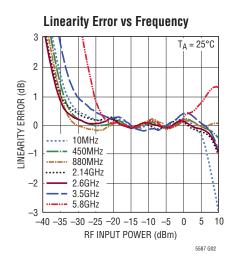
**Note 12:** The  $V_{DD}$  supply voltage can be the same as  $V_{CC}$  and the pins can share a common bypass capacitor of  $2.2\mu E$ 

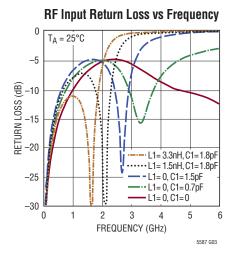


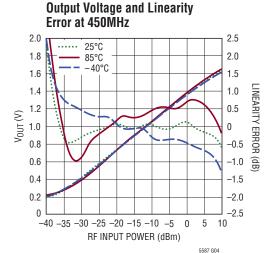
# TYPICAL PERFORMANCE CHARACTERISTICS

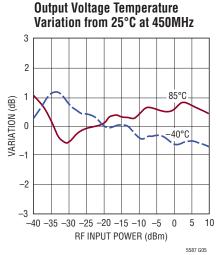
**TYPICHL PERFORMANCE CHARACTERISTICS**  $V_{CC} = V_{DD} = 0 V_{DD} = 3.3 V$ ,  $V_{REF} = 1.8 V$ , EN = 3.3 V,  $f_{SMPL} = f_{SMPL(MAX)}$  and  $f_{SCK} = f_{SCK(MAX)}$  unless otherwise noted.  $V_{OUT} = ADC$  Output (LSB) • 1.8/4096. Test circuit is shown in Figure 1.

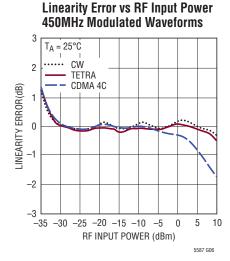


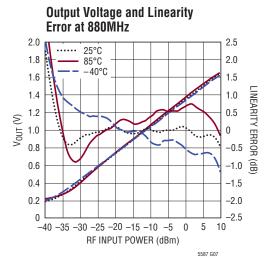


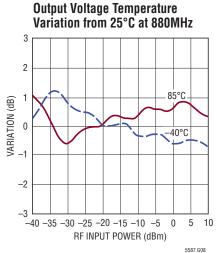


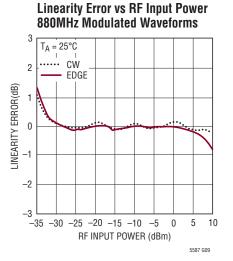






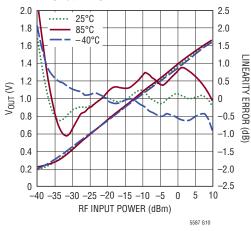




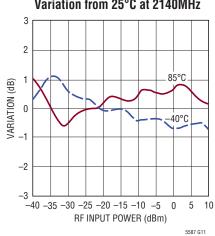


TYPICAL PERFORMANCE CHARACTERISTICS  $v_{CC} = v_{DD} = 0 v_{DD} = 3.3 v$ ,  $v_{REF} = 1.8 v$ , EN = 3.3 v,  $t_{SMPL} = t_{SMPL(MAX)}$  and  $t_{SCK} = t_{SCK(MAX)}$  unless otherwise noted.  $v_{OUT} = ADC$  Output (LSB) • 1.8/4096. Test circuit is shown in Figure 1.

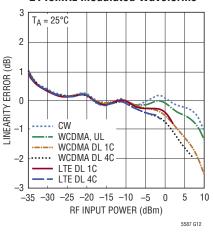
### **Output Voltage and Linearity** Error at 2140MHz



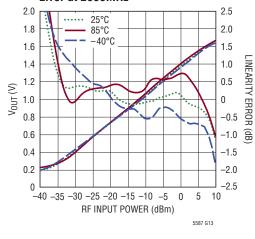
**Output Voltage Temperature** Variation from 25°C at 2140MHz



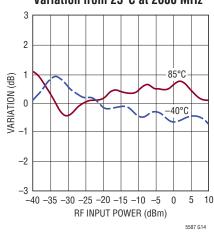
**Linearity Error vs RF Input Power** 2140MHz Modulated Waveforms



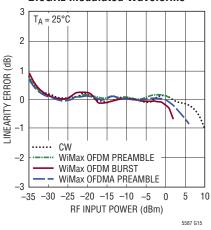
**Output Voltage and Linearity** Error at 2600MHz



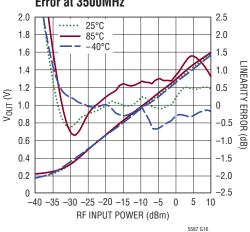
**Output Voltage Temperature** Variation from 25°C at 2600 MHz



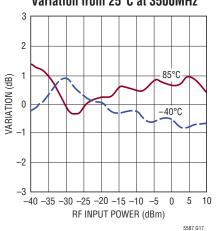
**Linearity Error vs RF Input Power** 2.6GHz Modulated Waveforms



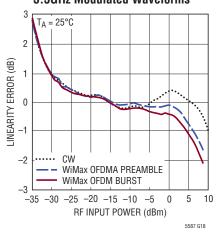
**Output Voltage and Linearity** Error at 3500MHz



**Output Voltage Temperature** Variation from 25°C at 3500MHz



**Linearity Error vs RF Input Power** 3.5GHz Modulated Waveforms

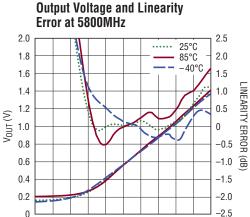


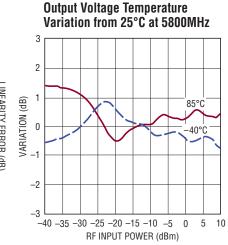
5

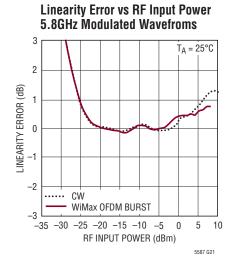
5587 G23

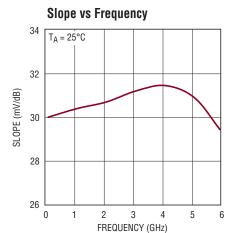
10

TYPICAL PERFORMANCE CHARACTERISTICS  $v_{CC} = v_{DD} = 0 v_{DD} = 3.3 v$ ,  $v_{REF} = 1.8 v$ , EN = 3.3 v,  $t_{SMPL} = t_{SMPL(MAX)}$  and  $t_{SCK} = t_{SCK(MAX)}$  unless otherwise noted.  $v_{OUT} = ADC$  Output (LSB) • 1.8/4096. Test circuit is shown in Figure 1.



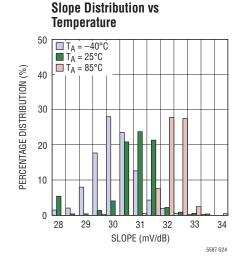


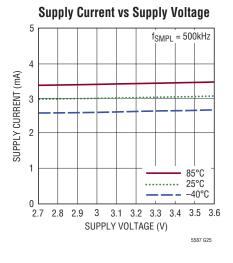


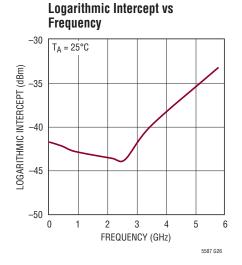


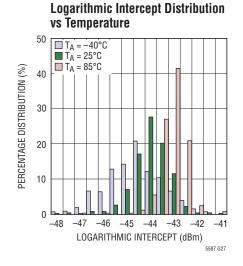
-40 -35 -30 -25 -20 -15 -10 -5

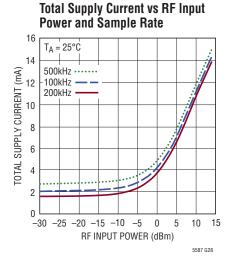
RF INPUT POWER (dBm)





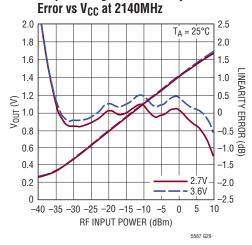




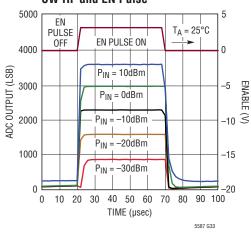


# **TYPICAL PERFORMANCE CHARACTERISTICS** $V_{CC} = V_{DD} = 0 V_{DD} = 3.3 V$ , $V_{REF} = 1.8 V$ , EN = 3.3 V, $I_{SMPL} = I_{SMPL(MAX)}$ and $I_{SCK} = I_{SCK(MAX)}$ unless otherwise noted. $I_{SMPL} = I_{SMPL(MAX)} = I_{SMP$

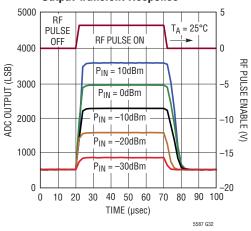
Output Voltage and Linearity



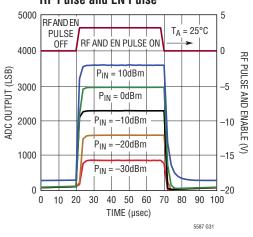
# Output Transient Response with CW RF and EN Pulse



**Output Transient Response** 



# Output Transient Response with RF Pulse and EN Pulse





#### PIN FUNCTIONS

**SDO (Pin 1):** Three-State Serial Data Output. The A/D conversion result is shifted out on SDO as a serial data stream with MSB first. The data stream consists of 12 bits of conversion data followed by trailing zeros.

**SCK (Pin 2):** Shift Clock Input. The SCK serial clock synchronizes the serial data transfer. SDO data transitions on the falling edge of SCK.

**OV**<sub>DD</sub> (**Pin 3**): ADC Output Driver Supply Voltage, 1.0V to 3.6V. OV<sub>DD</sub> should be bypassed with a 1 $\mu$ F ceramic capacitor. OV<sub>DD</sub> can be driven separately from V<sub>DD</sub> and OV<sub>DD</sub> can be higher than V<sub>DD</sub>.

 $V_{OUT}$  (Pin 4): Detector Analog Voltage Output. An internal series  $300\Omega$  resistor at the detector output allows for simple R-C filtering with a capacitor placed on this pin to GND. A 1000pF capacitor is recommended for a corner frequency of 500kHz.

 $C_{SQ}$  (Pin 6): Optional low-frequency range extension capacitor for frequencies below 250MHz. Connect 0.01 $\mu$ F from this pin to ground for 10MHz operation.

**RF** (**Pin 7**): RF Input Voltage. Should be externally DC-blocked. A capacitor of 1000pF is recommended. This pin has an internal  $205\Omega$  termination.

 $V_{CC}$  (Pin 8): Detector Power Supply Voltage, 2.7V to 3.6V. Can be connected to the  $V_{DD}$  voltage supply.  $V_{CC}$  should be bypassed with a 1μF ceramic capacitor. If  $V_{CC}$  and  $V_{DD}$  are tied together, then bypass with 2.2μF.

**EN (Pin 9):** Detector Enable. A logic low or no-connect on the enable pin shuts down the detector. A logic high enables the detector. An internal 500k pull-down resistor ensures the detector is off when the pin is left floating.

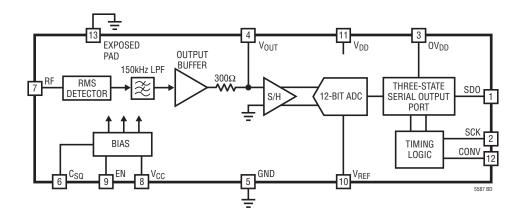
 $V_{REF}$  (Pin 10): ADC Reference Input Voltage.  $V_{REF}$  defines the input span of the ADC, OV to  $V_{REF}$ . The  $V_{REF}$  range is 1.4V to  $V_{DD}$ . Bypass to ground with a 1 $\mu$ F ceramic capacitor.

 $V_{DD}$  (Pin 11): ADC Power Supply Voltage, 2.7V to 3.6V.  $V_{DD}$  should be bypassed with a 1µF ceramic capacitor.

**CONV (Pin 12):** Convert Input. This active high signal starts a conversion on the rising edge. The ADC automatically powers down after conversion. A logic low on this input enables the SDO pin, allowing the data to be shifted out.

**GND** (Pin 5, Exposed Pad Pin 13): Ground. For high-frequency operation, backside ground connection should have a low-inductance connection to the pcb ground using many through-hole vias. See layout information.

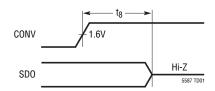
### **BLOCK DIAGRAM**



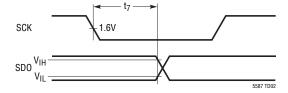
LINEAR TECHNOLOGY

# **TIMING DIAGRAMS**

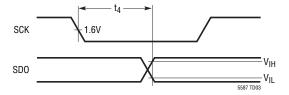
#### SDO Into Hi-Z State After CONV Rising Edge



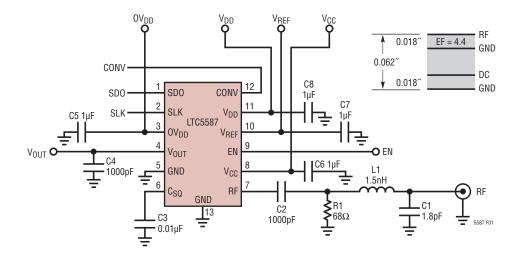
#### SDO Data Valid Hold Time After SCK Falling Edge



#### SDO Data Valid Access Time After SCK Falling Edge



#### **TEST CIRCUIT**



REF DES	VALUE	SIZE	PART NUMBER
C5, C6, C7, C8	1μF	0402	AVX 0402ZG105ZAT2A
C3	0.01µF	0402	AVX 04023C103KAT2A
C2, C4	1000pF	0402	AVX 04025C102KAT2A
R1	68Ω	0402	CRCW040268R1FKED

FREQUENCY	RF <sub>IN</sub> I	WATCH
RANGE	L1	C1
0.04 to 1.8GHz	3.3nH	1.8pF
1.75 to 2.2GHz	1.5nH	1.8pF
2.4 to 2.9GHz	0	1.5pF
2.8 to 3.8GHz	0	0.7pF
4.5 to 6.0GHz	0	0

Figure 1. Evaluation Circuit Schematic

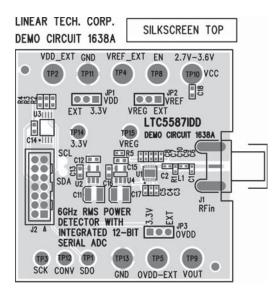


Figure 2. Evaluation Circuit Board

#### Operation

The LTC5587 combines a proprietary high-speed power detector with an internal 150kHz lowpass averaging filter and a true 12-bit successive approximation ADC with a serial output interface. It can accurately measure the RMS power of high crest-factor modulated RF signals. The output voltage of the RF power detector is converted to a 12-bit digital word that is directly proportional to the average RF input power in dBm. The part can be operated from a single supply or dedicated supplies, allowing the user to select a specific voltage range for the ADC conversion in addition to interfacing with 1.8V, 2.5V, or 3V digital systems.

#### **Evaluation**

Figure 1 shows the simplified evaluation circuit schematic, and Figure 2 shows the associated board artwork. To ensure proper operation, good grounding practice should be followed in the board layout, with liberal placement of vias under the exposed pad of the package and around signal and digital lines. The evaluation board shown in Figure 2 contains additional support circuitry not shown in Figure 1 that includes an optional 3.3V regulator for the  $V_{DD}$ ,  $OV_{DD}$ , and  $V_{CC}$  supplies and an optional 1.8V regulator for the  $V_{RFF}$ reference. This onboard reference provides good accuracy (less than ±5mV) over temperature, contributing less than ±0.1dB error to the ADC output. To evaluate the digital output, the QuickEval PC-based software can be used with the DC590B USB controller interface board. This board contains a generic USB to serial peripheral interface (SPI) controller. A 14-pin ribbon cable connects the evaluation board to the DC590B board. The DC590B allows the evaluation at approximately a 200Hz sample rate ( $f_{SMPl}$ ). (See http://cds.linear.com/docs/Reference%20Design/dc590B. pdf). For higher sample rates the digital I/O pins can be accessed directly on the board. Contact LTC Applications for more information on higher sample rate evaluation.

#### **RF Input Matching**

The input resistance is about  $205\Omega$ . Input capacitance is 1.6pF. The impedance vs frequency of the RF input is detailed in the following table.

Table 1. RF Input Impedance

FREQUENCY	INPUT	<b>\$11</b>			
(MHz)	IMPEDANCE (Ω)	MAG	ANGLE (°)		
10	203.3-j1.4	0.605	-0.7		
50	201.8-j7.0	0.605	-3.7		
100	197.2-j13.7	0.606	-7.3		
200	161.9-j25.8	0.608	-14.6		
400	142.5-j43.6	0.614	-28.9		
500	125.3-j48.5	0.619	-35.8		
800	88.0-j60.4	0.636	-55.6		
900	79.2-j62.6	0.643	-61.8		
1000	71.8-j64.3	0.650	-67.7		
1500	46.6-j68.8	0.685	-94.3		
2000	31.1-j69.2	0.715	-116		
2100	29.9-j69.0	0.721	-119.9		
2500	22.4-j66.8	0.739	-134.1		
3000	15.3-j60.7	0.756	-149.6		
3500	3500 9.9-j47.3 0.768		-163.2		
4000	6.6-j16.9 0.779		-175.5		
5000	9.8-j51.7 0.787		162.1		
6000	18.5-j69.4	0.792	141.4		

A shunt  $68\Omega$  resistor can be used to provide a broadband match at low frequencies up to 1GHz and from 4.5GHz to 6GHz. As shown in Figure 3, a nominal broadband input match can be achieved up to 1.8GHz by using an LC matching circuit consisting of a series 3.3nH inductor (L1) and a shunt 1.8pF capacitor (C1). This match will maintain a return loss of about 10dB across the band. For matching at higher frequencies, L1 and C1 values are listed in the table of Figure 1. The input reflection coefficient referenced to the RF input pin with no external components is shown on the smith chart in Figure 4. Alternatively, it is possible to match using an impedance transformation network by omitting R1 and transforming the  $205\Omega$  input to  $50\Omega$ . This narrow band matching will improve sensitivity up to about 6dB max, and the dynamic range remains the same. For example: by omitting R1 and setting L1 = 1.8nH and C1 = 3pF, a 2:1 VSWR match can be obtained from 1.95GHz to 2.36GHz with a sensitivity improvement of 5dB.

The RF input DC-blocking capacitor (C2) and  $C_{SQ}$  bias decoupling capacitor (C3), can be adjusted for low-frequency operation. For input frequencies down to 10MHz, 0.01 $\mu$ F is needed at  $C_{SQ}$ . For frequencies above 250MHz, the on-chip 20pF decoupling capacitor is sufficient and  $C_{SQ}$  may be eliminated as desired. The DC-blocking capacitor can be as large as 2200pF for 10MHz operation or 100pF for 2GHz operation. A DC-blocking capacitor larger than 2200pF results in an undesirable RF pulse response on the falling edge due to the rectifier action of the diode limiter/ESD protection at the RF pin. Therefore, the recommended value for C2 for general applications is conservatively set at 1000pF.

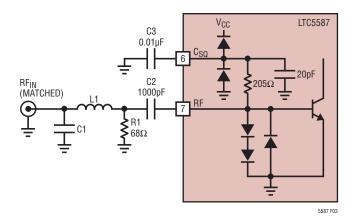


Figure 3. Simplified Schematic of the RF Input Interface

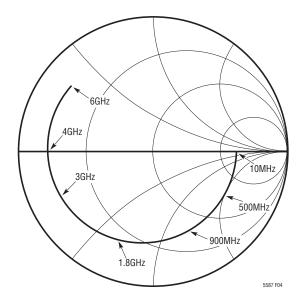


Figure 4. Input Reflection Coefficient

#### **Filter Capacitor**

The interface of the  $V_{OUT}$  pin of the LTC5587 is shown in Figure 5. It includes a push-pull output stage with a series  $300\Omega$  resistor. The detector output stage is capable of sourcing and sinking 5mA of current. The  $V_{OUT}$  pin can be shorted to GND or  $V_{CC}$  (or  $V_{DD}$  whichever is lower) without damage, but going beyond the  $V_{CC}$  + 0.5V or  $V_{DD}$  + 0.5V and alternatively going beyond GND – 0.5V may result in damage as the internal ESD protection diodes will start to conduct excessive current.

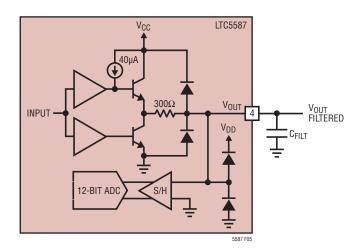


Figure 5. Simplified Schematic of the Detector Analog Output

The residual ripple due to RF modulation can be reduced by adding an external capacitor,  $C_{FILT}$  (C4 on evaluation circuit schematic) to the  $V_{OUT}$  pin to form a simple RC lowpass filter. The internal  $300\Omega$  resistor in series with the output pin enables filtering of the output signal with just the addition of  $C_{FILT}$ . The filter –3dB corner frequency,  $f_{C}$ , can be calculated with the following equation:

$$f_{C(-3dB)} = 1/(2 \cdot \pi \cdot 300 \cdot C_{FILT})$$

with  $f_C$  in Hz and  $C_{FILT}$  in F. Since the bandwidth of the detected signal is effectively limited by the internal 150kHz filter, a choice of  $C_{FILT}$  = 1000pF sets the ADC –3dB input bandwidth at 530kHz and does not affect the residual modulation ripple much.  $C_{FILT}$  has a small effect on ADC sampling accuracy. For example, when the sample rate of the ADC is changed from 25ksps to 500ksps, the output value changes less than 0.2dB with any choice of  $C_{FILT}$ .

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5587

Figure 6 shows the effect of the external filter capacitor on the residual ripple level for a 4-carrier WCDMA downlink signal at 2.14GHz with -10dBm. Adding a  $0.047\mu\text{F}$  capacitor to the output decreases the peak-to-peak output ripple from 150LSB to about 60LSB.

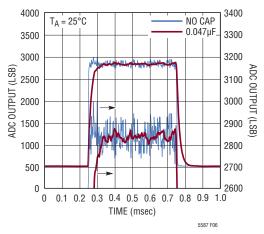


Figure 6. Residual Ripple, Output Transient Response for RF Pulse with WCDMA 4-Carrier Modulation

Figure 7 shows the transient response for a 2.6GHz WiMax signal with preamble and burst ripple reduced by a factor of three using a 0.047µF external filter capacitor. The average power in the preamble section is –10dBm, while the burst section has 3dB lower average power. With the capacitor, the ripple in the preamble section is about 0.5dB peak to peak. The modulation used was OFDM (WiMax 802.16-2004) MMDS band 1.5MHz BW, with 256 size FFT and 1 burst at QPSK 3/4.

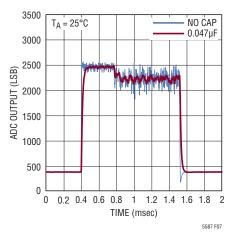


Figure 7. Residual Ripple for 2.6GHz WiMax OFDM 802.16-2004

Figure 8 shows how the peak-to-peak ripple decreases with increasing external filter capacitance value. Also shown is how the RF pulse response will have longer rise and fall times with the addition of this lowpass filter cap.

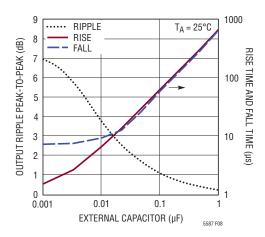


Figure 8. Residual Ripple, Output Transient Times for RF Pulse with WCDMA 4-Carrier Modulation vs External Filter Capacitor C4

Figure 9 shows the rise time and fall time is a strong function of the RF input power when the filter capacitor is not present.

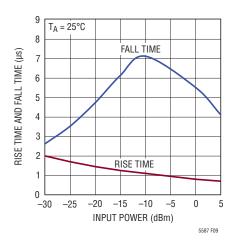


Figure 9. RF Pulse Response Rise Time and Fall Time vs RF Input Power



For a given RF modulation type, WCDMA for example, the internal 150kHz filter provides nominal filtering of the residual ripple level. Additional external filtering happens in the log-domain, which introduces a systematic log-error in relation to the signal's crest factor as shown in the following equation in dB<sup>1</sup>:

$$Error|_{dB} = 10 \cdot log_{10}(r + (1-r)10^{-CF/10}) - CF \cdot (r-1)$$

Where CF is the crest factor and r is the duty cycle of the measurement (or number of measurements made at the peak envelope divided by the total number of periodic measurements in the measurement period). It is important to note that the CF refers to the 150kHz low-pass filtered envelope of the signal. The error will depend on the statistics and bandwidth of the modulation signal in relation to the internal 150kHz filter. For example: simulations have shown for the case of WCDMA that it is possible to set the external filter capacitor corner frequency at 15kHz and only introduce an error less than 0.1dB.

Figure 10 shows the output AC modulation ripple as a function of modulation difference frequency for a 2-tone input signal at 2140MHz with -10dBm input power. The resulting deviation in the output voltage of the detector shows the effect of the internal 150kHz filter.

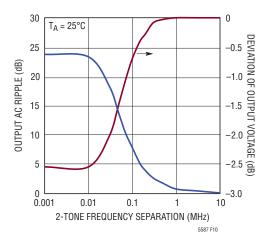


Figure 10. Output DC Voltage Deviation and Residual Ripple vs 2-Tone Separation Frequency

The output voltage noise density and integrated noise are shown respectively in Figures 11 and 12 for various input power levels. The noise is a strong function of input level and there is roughly a 10dB improvement in the output noise level for an input level of 0dBm versus no input.

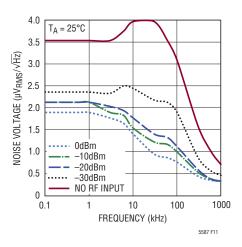


Figure 11. Output Voltage Noise Density

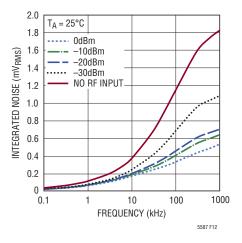


Figure 12. Integrated Output Voltage Noise

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<sup>1.</sup> Steve Murray, "Beware of Spectrum Analyzer Power Averaging Techniques," Microwaves & RF, Dec. 2006.

The total noise at the ADC output is dominated by the output noise of the detector, and the sampling noise is insignificant. The peak-to-peak output noise is also almost independent of the sample rate. Figure 13 shows the peak-to-peak noise at the ADC output as a function of the RF input level for a CW RF input. Increasing  $C_{FILT}$  from 1000pF to 0.01µF gives roughly 2x to 3x lower noise over input power.

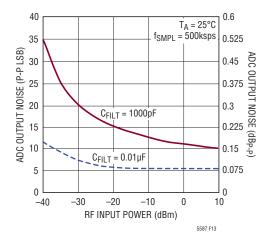


Figure 13. Peak-to-Peak Noise at ADC Output vs RF Input Power

#### **Serial Interface**

The LTC5587 communicates with microcontrollers, DSPs and other external circuitry via a 3-wire interface. Figure 14 shows the operating sequence of the serial interface.

#### **Data Transfer**

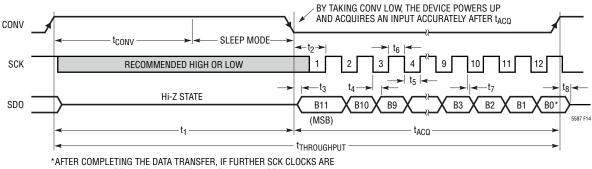
A rising CONV edge starts a conversion and disables SDO. After the conversion, the ADC automatically goes into sleep mode, drawing only leakage current. CONV going low enables SDO and clocks out the MSB bit, B11. SCK then synchronizes the data transfer with each bit being transmitted on the falling SCK edge and can be captured on the rising SCK edge. After completing the data transfer, if further SCK clocks are applied with CONV low, SDO will output zeros indefinitely (see Figure 14). For example, 16-clocks at SCK will produce the 12-bit data and four trailing zeros on SDO.

#### Sleep Mode

The LTC5587 ADC enters sleep mode to save power after each conversion if CONV remains high. In sleep mode, all bias currents are shut down and only leakage currents remain (about  $0.1\mu A$ ). The sample-and-hold is in hold mode while the ADC is in sleep mode. The ADC returns to sample mode after the falling edge of CONV during power-up.

#### **Exiting Sleep Mode and Power-Up Time**

By taking CONV low, the ADC powers up and acquires an input signal completely after the acquisition time ( $t_{ACQ}$ ). After  $t_{ACQ}$ , the ADC is ready to perform a conversion again by a rising edge on CONV.



APPLIED WITH CONV LOW, THE ADC WILL OUTPUT ZEROS INDEFINITELY

Figure 14. LTC5587 Serial Interface Timing Diagram



#### **Conversion Range**

The  $V_{REF}$  pin defines the full-scale range of the ADC. The reference voltage can range from  $V_{DD}$  down to 1.4V. If the difference between the input voltage on the  $V_{OUT}$  pin and GND exceeds  $V_{REF}$ , the output code will stay fixed at all ones, and if this difference goes below 0V, the output code will stay fixed at all zeros. Figure 15 shows the ideal input/output characteristics for the ADC. The code transitions occur midway between successive integer LSB values (i.e., 0.5LSB, 1.5LSB, 2.5LSB, ..., FS – 1.5LSB). The output code is straight binary with 1LSB =  $V_{REF}/4096$ . Using the onboard 1.8V reference on the evaluation board, the conversion range can be easily calculated between LSB and dBm. For an analog output slope of 32mV/dB, we can calculate the total 40dB range is equivalent to 2912.7LSB's at the ADC output:

40dB = (40dB • 4096LSB • 32mV/dB)/1.8V = 2912.7LSB

#### **Detector Enable Pin**

A simplified schematic of the EN pin is shown in Figure 16. To enable the LTC5587 detector it is necessary to put greater than 2V on this pin. To disable or turn off the detector, this voltage should be below 0.3V. At an enable voltage of 3.3V the pin draws roughly  $20\mu A$ . If the EN pin is not connected, the detector circuitry is disabled through an internal 500k pull-down resistor.

It is important that the voltage applied to the EN pin should never exceed  $V_{CC}$  by more than 0.5V. Otherwise, the supply current may be sourced through the upper ESD protection diode connected at the EN pin.

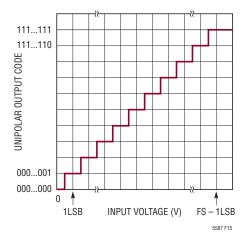


Figure 15. ADC Transfer Characteristics

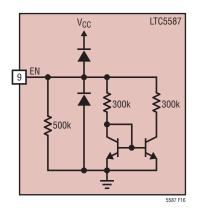
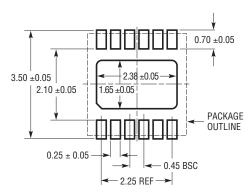


Figure 16. Enable Pin Simplified Schematic

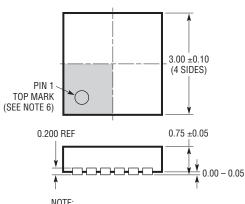
#### PACKAGE DESCRIPTION

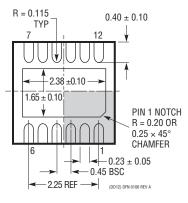
#### **DD Package** 12-Lead Plastic DFN (3mm × 3mm)

(Reference LTC DWG # 05-08-1725 Rev A)



**RECOMMENDED** SOLDER PAD PITCH AND DIMENSIONS APPLY SOLDER MASK TO AREAS THAT ARE NOT SOLDERED





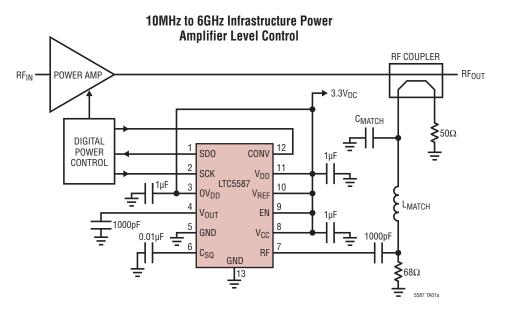
BOTTOM VIEW-EXPOSED PAD

#### NOTE:

- 1. DRAWING IS NOT A JEDEC PACKAGE OUTLINE
- 2. DRAWING NOT TO SCALE
- 3. ALL DIMENSIONS ARE IN MILLIMETERS
- 4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE 5. EXPOSED PAD AND TIE BARS SHALL BE SOLDER PLATED
- 6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE



## TYPICAL APPLICATION



## **RELATED PARTS**

PART NUMBER	DESCRIPTION	COMMENTS
RF Power Detec	tors	
LTC5505	RF Power Detectors with >40dB Dynamic Range	300MHz to 3GHz, Temperature Compensated, 2.7V to 6V Supply
LTC5507	100kHz to 1000MHz RF Power Detector	100kHz to 1GHz, Temperature Compensated, 2.7V to 6V Supply
LTC5508	300MHz to 7GHz RF Power Detector	44dB Dynamic Range, Temperature Compensated, SC70 Package
LTC5509	300MHz to 3GHz RF Power Detector	36dB Dynamic Range, Low Power Consumption, SC70 Package
LTC5530	300MHz to 7GHz Precision RF Power Detector	Precision V <sub>OUT</sub> Offset Control, Shutdown, Adjustable Gain
LTC5531	300MHz to 7GHz Precision RF Power Detector	Precision V <sub>OUT</sub> Offset Control, Shutdown, Adjustable Offset
LTC5532	300MHz to 7GHz Precision RF Power Detector	Precision V <sub>OUT</sub> Offset Control, Adjustable Gain and Offset
LT5534	50MHz to 3GHz Log RF Power Detector with 60dB Dynamic Range	±1dB Output Variation over Temperature, 38ns Response Time, Log Linear Response
LTC5536	Precision 600MHz to 7GHz RF Power Detector with Fast Comparator Output	25ns Response Time, Comparator Reference Input, Latch Enable Input, –26dBm to +12dBm Input Range
LT5537	Wide Dynamic Range Log RF/IF Detector	Low Frequency to 1GHz, 83dB Log Linear Dynamic Range
LT5538	75dB Dynamic Range 3.8GHz Log RF Power Detector	±0.8dB Accuracy Over Temperature
LTC5582	60dB Dynamic Range RMS Detector	40MHz to 10GHz, ±0.5dB Accuracy Over Temperature
LT5581	6GHz RMS Power Detector, 40dB Dynamic Range	±1dB Accuracy Over Temperature, Log Linear Response, 1.4mA at 3.3V
Infrastructure		
LT5568	700MHz to 1050MHz High Linearity Direct Quadrature Modulator	22.9dBm OIP3 at 850MHz, $-160.3$ dBm/Hz Noise Floor, $50\Omega$ , $0.5V_{DC}$ Baseband Interface, 3-Ch CDMA2000 ACPR = $-71.4$ dBc at 850MHz
LT5572	1.5GHz to 2.5GHz High Linearity Direct Quadrature Modulator	21.6dBm OIP3 at 2GHz, –158.6dBm/Hz Noise Floor, High-Ohmic 0.5V <sub>DC</sub> Baseband Interface, 4-Ch W-CDMA ACPR = –67.7dBc at 2.14GHz
LT5579	1.5GHz to 3.8GHz High Linearity Upconverting Mixer	27.3dBm OIP3 at 2.14GHz, 9.9dB NF, 2.6dB Conversion Gain, –35dBm LO Leakage
LTC5598	5MHz to 1600MHz High Linearity Direct Quadrature Modulator	27.7dBm OIP3 at 140MHz, -161.2dBm/Hz Noise Floor, 0.5V <sub>DC</sub> Baseband Interface, -55dBm LO Leakage and 50.4dBc Image Rejection at 140MHz
LTC5588-1	200MHz to 6GHz Very High Linearity Direct Quadrature Modulator	30dBm OIP3 at 2.14GHz, Optimizable to 35dBm, -160.5dBm/Hz Output Noise Floor, 0.5V <sub>DC</sub> Baseband Interface